## A perturbative study of delocalisation transition in one-dimensionalmodels with long-range correlated disorder

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## A bstract

We study the delocalisation transition which takes places in onedimensional disordered systems when the random potential exhibits speci c long-range correlations. We consider the case of weak disorder; using a systematic perturbative approach, we show how the delocalisation transition brings about a change of the scaling law of the inverse localisation length which ceases to be a quadratic function of the disorder strength and assumes a quartic form when the threshold separating the localised phase from the extended one is crossed.

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Recently, one-dimensional (1D) models with correlated disorder have become the object of intense scrutiny, as a consequence of the discovery that specie clong-range correlations of the random potential can create a continuum of extended states and give rise to mobility edges [1, 2]. The emergence of a phase of extended states implies that, when the disorder exhibits appropriate long-range spatial correlations, even 1D models can display a metalinsulator transition analogous to the Anderson transition which takes place in three-dimensional disordered system s. A lthough the results of the works [1, 2] were obtained for discrete lattices, it was soon found that long-range correlations can produce analogous phenomena also in continuous disordered m odels  $[\beta]$ . The m obility edge predicted in [2] received an experimental con-

Im ation in [4], where the phenom enon was observed in the transmission of microwaves in a single-mode guide with a random array of correlated scatterers. Further progress along this line of research would make possible the realization of 1D devices with speci ed mobility edges which could be used as window lters in electronic, acoustic or photonic structures, as suggested in [5].

The theoretical and practical in portance of the delocalisation transition in 1D m odels m akes desirable to obtain a complete understanding of the role played by correlations in the formation of mobility edges. Unfortunately, the theoretical comprehension of the phenomenon achieved in [2] and in the successive analytical works is not totally satisfactory, because it rests on the assumption of weak disorder and on the use of a second-order approxim ation scheme. Thus, the delocalisation transition has been de ned by the condition that the second-order term of the inverse localisation length (or Lyapunov exponent) vanish over a continuum interval of electronic energies, while higher-order terms of the Lyapunov exponent have been completely neglected. This simplifying approach is elective but incomplete, because it does not clarify the true nature of the \extended" states, leaving open the question of whether they are completely delocalised or not. The aim of this work is to shed light on this point and thus provide a better understanding of the delocalisation transition in 1D models. To this end, we make use of a system atic perturbative approach that allows us to compute the fourthorder term of the Lyapunov exponent. A m ed with this result, we are able to ascertain the nature of the extended states and to discuss the di erences between G aussian and non-G aussian potentials which appear in the localisation properties of 1D models at this rened level of description.

In what follows, we consider the Ham iltonian continuous model de ned by the Schrodinger equation

$$(h^2 = 2m)^{(0)}(x) + "U(x) (x) = E(x)$$
 (1)

which describes an electron of energy E moving under the in uence of a random potential U (x). We study the case of weak disorder, identi ed by the condition "! 0. To simplify the form of the equations, in the rest of this paper we adopt a system of units such that  $h^2 = 2m = 1$ . We consider electrons of positive energy, so that we can write  $E = k^2$ ; since the wavevector k enters model (1) only via the energy, we can restrict our attention to the case k > 0 without loss of generality.

We de ne the statistical properties of the disorder through the moments of the potential U (x). We assume that the model under study is spatially hom ogeneous in the mean; as a consequence, the n-th moment of the potential

$$(x_1;x_2;:::;x_{n-1}) = hU(x)U(x + x_1):::U(x + x_{n-1})i$$

depends only on n 1 relative coordinates. Here and in the following we use angular brackets h:::i to denote the average over disorder realizations. We also want the average features of model (1) to be invariant under a change of sign of the potential; therefore we assume that all moments of odd order vanish. Finally, for the sake of mathematical convenience, we tem porarily suppose that a correlation length  $l_c$  can be de ned such that the values U (x<sub>1</sub>) and U (x<sub>2</sub>) of the potential are statistically independent when the distance between the points x<sub>1</sub> and x<sub>2</sub> is much larger than  $l_c$ . To study the case of long-range correlations, we will subsequently relax this hypothesis by taking the lim it  $l_c ! 1$ .

To determ ine the average behaviour of the eigenstates of Eq. (1), we introduce the inverse localisation length

$$(k) = \lim_{x! = 1} \frac{1}{4x} \ln h^{2}(x)k^{2} + \frac{\alpha}{2}(x)i:$$
 (2)

As a rst step to compute the Lyapunov exponent (2), we derive a di erential equation for  ${}^{2}(x)$  and  ${}^{(2)}(x)$ . U sing Eq. (1) as a starting point, it is easy to show that the vector

$$u(x) = \overset{0}{\overset{2}{(x)}} \qquad \overset{2}{(x)} \overset{1}{\overset{2}{(x)}} \\ \overset{0}{(x)=k^{2}} \overset{2}{\overset{0}{(x)=k^{2}}} \overset{1}{\overset{0}{(x)=k^{2}}} \\ \overset{0}{(x)} \overset{0}{(x)=k} \overset{0}{(x)=k^{2}} \overset{1}{\overset{0}{(x)=k^{2}}}$$

obeys the equation

$$\frac{\mathrm{d}u}{\mathrm{d}x} = (\mathbf{A} + \mathbf{"} (\mathbf{x})\mathbf{B})\mathbf{u}; \tag{3}$$

where  $(x) = U(x)=k^2$  is the scaled potential and the symbols A and B stand for the matrices

$$A = \begin{bmatrix} 0 & 0 & 2k & & 0 & 0 & 1 \\ 0 & 0 & 2k & & 0 & 0 & 0 \\ 0 & 0 & 2k & \text{and} & B = \begin{bmatrix} 0 & 0 & 0 & 2k & A \\ 0 & 0 & 2k & A \end{bmatrix}$$

At this point our problem consists in extracting information on the average vector hu(x)i from the stochastic equation for u(x); this can be done using

a method developed by Van Kampen [6], which replaces Eq. (3) with an ordinary di erential equation of the form

$$\frac{dhu(x)i}{dx} = K(x)hu(x)i; \qquad (4)$$

The generator K (x) in Eq. (4) is a sure operator that can be expressed in term s of a cumulant expansion

$$K(x) = \int_{n=0}^{x^{2}} W^{n} K_{n}(x)$$
(5)

where the partial generators  $K_n(x)$  are functions of speci c combinations (known as \ordered cumulants") of the moments of the random matrix

$$M(x) = (x) \exp(Ax) \exp(Ax)$$
: (6)

Van K am pen has established a set of system atic rules for constructing all the terms of the series (5); applying his prescriptions one obtains that all generators of odd order are zero because the odd m om ents of the potential vanish. As for the even-order generators, the zero-th order term has the simple form K<sub>0</sub> = A, which corresponds to ignoring the random potential. The rst term where disorderm anifests its e ect is the second-order generator

$$K_{2}(x) = \int_{0}^{Z_{x}} dx_{1} \exp (A x) M (x)M (x_{1})iexp (A x);$$

which is proportional to the two-point correlator; a re nem ent of this result is obtained by taking into account the fourth-order term

$$K_{4}(x) = {}^{R_{x}}_{0} dx_{1} {}^{R_{x_{1}}}_{0} dx_{2} {}^{R_{x_{2}}}_{0} dx_{3} exp (A x)$$
  

$$[M (x)M (x_{1})M (x_{2})M (x_{3})i$$
  

$$M (x)M (x_{1})iM (x_{2})M (x_{3})i$$
  

$$M (x)M (x_{2})iM (x_{1})M (x_{3})i$$
  

$$M (x)M (x_{3})iM (x_{1})M (x_{2})i]exp (A x)$$

whose integrand constitutes a non-trivial example of ordered cum ulant of the matrix (6). A lthough the nules of Van K ampen make possible to derive every partial generator K<sub>n</sub>(x), for the purpose of this work we can truncate the series (5) and neglect all terms of higher order than the fourth. As can be seen from Eq. (4), the behaviour of hu(x) i for x ! 1 is determined by the

eigenvalue with the largest real part of the asymptotic generator K (1) =  $\lim_{x! 1} K(x)$ ; we are thus led to the conclusion that, in order to determ ine the Lyapunov exponent (2) with fourth-order accuracy, we have to solve the secular equation for the truncated asymptotic generator

$$\overline{K} (1) = A + {"}^{2}K_{2} (1) + {"}^{4}K_{4} (1):$$
(7)

Carrying out the calculations, one obtains that the inverse localisation length (2) can be written as

$$(k) = \mathbf{u}^{2}_{2}(k) + \mathbf{u}^{4}_{4}(k) + \mathbf{u}^{(\text{G})}(k) + \mathbf{u}^{(\text{NG})}(k) + \mathbf{o}^{(\text{NG})}(k)$$
(8)

where the second-order term has the standard form

$$_{2}(\mathbf{k}) = \frac{1}{4k^{2}} \int_{0}^{2} \int_{1}^{2} d\mathbf{x} \cos(2k\mathbf{x}) d\mathbf{x}$$
(9)

As for the fourth-order term of the Lyapunov exponent (8), its rst component can be written as

where the functions  $'_{c}(k;x)$  and  $'_{s}(k;x)$  are de ned as

$$'_{c}(k;x) = \frac{R_{1}}{R_{1}} _{2}(y)\cos(2ky)dy$$
  
 $'_{s}(k;x) = \frac{R_{1}}{x} _{2}(y)\sin(2ky)dy$ 

The second component turns out to be

where the symbol  $_4(x_1;x_2;x_3)$  represents the fourth cum ulant of the random potential. These form ulae show that, in contrast to the relative simplicity of the second-order result (9), the fourth-order terms (10) and (11) exhibit a non-trivial dependence on the binary correlator and on the fourth cum ulant, respectively. The greater complexity of the results is a consequence of the more sophisticated description of localisation, which is visualised as

an interference e ect generated by double scatterings of the electron in the second-order scheme, whereas the fourth-order approximation also takes into account quadruple scattering processes. Them ore accurate description of the localisation processes makes possible to draw a distinction between Gaussian and non-Gaussian disorders. These two classes of random potentials are necessarily undi erentiated within the fram ework of the second-order approximation, since the second-order Lyapunov exponent (9) depends only on the second m om ent of the potential; in the fourth-order description, how ever, the di erences between the two kinds of potentials em erge in the component (11) which, being a function of the cum ulant, vanishes if, and only if, the disorder is Gaussian. In conclusion, the separation of the fourth-order term of the Lyapunov exponent in the two components (10) and (11) is justified by the distinct physical character of these two parts: while the form er is common to all Gaussian and non-Gaussian potentials with the same two-point correlation function, the latter describes the speci c e ect of the non-G aussian nature of the disorder.

To analyse the case of disorder with long-range correlations, we evaluated the form taken by expressions (9) and (10) when the correlation function is

$$_{2}(\mathbf{x}) = _{2} \frac{\sin(2k_{c}\mathbf{x})}{\mathbf{x}} \exp(\mathbf{x} = \mathbf{l}_{c})$$
 (12)

and we subsequently took the lim it  $l_{\rm c}$  ! ~1 , which reduces the correlation function to the form

$$_{2}(\mathbf{x}) = _{2} \frac{\sin (2k_{c}\mathbf{x})}{\mathbf{x}}$$
: (13)

This approach is generally successful, but it fails for  $k = k_c$  because for this value of the wavevector the asymptotic lim it of the generator (5) exists only as long as  $l_c$  is nite. Our results for the Lyapunov exponent, therefore, are not valid in a small neighbourhood of  $k_c$ .

Inserting the correlation function (12) in Eq. (9) and taking the limit  $l_{\rm c}$  ! 1 , one obtains that the second-order Lyapunov exponent has the form

$${}_{2}(\mathbf{k}) = \begin{pmatrix} \frac{2}{8k^{2}} & \text{for } 0 < k < k_{c} \\ 0 & \text{for } k_{c} < k \end{pmatrix}$$
(14)

Eq. (14) shows that long-range correlations of the form (13) m ake the secondorder Lyapunov exponent vanish when the wavevector k exceeds a critical value  $k_c$ . This result was interpreted in [2] as evidence that long-range correlation of the potential can create a continuum of extended states, with a m obility edge at  $k = k_c$ . Second-order theory, however, cannot precise the nature of the \extended" states nor de ne their spatial extension. To overcom e this limit, one can com pute the fourth-order term (10) of the Lyapunov exponent. Evaluating expression (10) for the correlation function (12) and then taking the limit  $l_c$ ! 1, one arrives at the result

$$\overset{(G)}{\underset{4}{\otimes}} (k) = \overset{8}{\underset{2}{\otimes}} (k) \text{ for } 0 < k < k_{c}$$

$$\overset{(G)}{\underset{4}{\otimes}} (k) = \overset{2}{\underset{2}{\otimes}} (k) \text{ for } k_{c} < k < 2k_{c}$$

$$\overset{(G)}{\underset{4}{\otimes}} (k) = \overset{2}{\underset{2}{\otimes}} (k) \text{ for } k_{c} < k < 2k_{c}$$

$$(15)$$

where the functions  $_1$  (k) and  $_2$  (k) are dened as

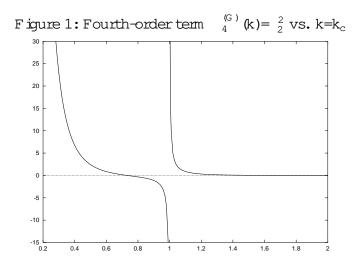
$$\frac{1}{1} (k) = \frac{2}{4k^4} \frac{5}{32k} \ln \frac{k+k_c}{k-k_c}^2 \frac{k^2+k_c+k_c^2}{8k_c(k_c^2-k^2)} I(k)$$

$$\frac{2}{4k^4} \frac{k}{8k} \ln \frac{k+k_c}{k-k_c}^2 + \frac{2k_c-k}{8k_c(k-k_c)} I(k)$$

with

$$I(k) = \int_{0}^{Z_{1}} si^{2} (2k_{c}x) \cos(2kx) dx$$
:

The symbol  $s_{x}(x)$  in the previous equation represents the sine integral de ned as  $s_{x}(x) = \frac{R_{1}^{2}}{x} dt sin(t) = t$ . In Fig. 1 we show the plot of the fourth-order Lyapunov exponent (15) as a function of the wavevector k. As already ob-



served, the divergence for  $k = k_c m$  ust be disregarded because the asymptotic

generator (7) is not de ned for this value of the wavevector in the lim it of long-range correlations. In the interval  $0 < k < k_c$  the second-order Lyapunov exponent (14) is positive and the fourth-order term (15) constitutes just a sm all correction which enhances or decreases the localisation of electronic states according to whether it assumes positive or negative values. The main interest of Eq. (15), however, lies in the fact that it shows that the fourth-order Lyapunov exponent is positive in the interval  $k_c < k < 2k_c$ , where the second-order term (14) vanishes. This result clari es the nature of the mobility edge at  $k = k_c$ : the electronic states are exponentially localised on both sides of the threshold, but the localisation length is increased by a factor 0 (1="<sup>2</sup>) when the wavevector exceeds the critical value  $k_c$ . For weak disorder, the corresponding change in the electron mobility is so conspicuous that one can legitim ately speak of \delocalisation transition", even if the \extended" states are not completely delocalised like B loch states in a crystal lattice. A second noteworthy aspect of the fourth-order term (15) is that it vanishes for  $k > 2k_{\rm c}$  so that, in the case of G aussian disorder, a second transition takes place at  $k = 2k_c$  with the electrons becoming even m ore delocalised.

So far our discussion has been centred on the term (10), which allows a complete analysis of G aussian potentials. For non-G aussian disorder, how – ever, one must also take into account the term (11) which enhances localisation. As an example, one can consider the case of a non-G aussian potential with long-range binary correlations of the form (13) and with an exponentially decaying fourth cumulant

$$_{4} (x; y; z) = _{4} \exp \left[ (jxj + jyj + jzj) \right]:$$
(16)

In this case the fourth-order term of the Lyapunov exponent is the sum of the component (15) and of the additional term

$${}_{4}^{(NG)}(k) = \frac{15_{4}}{8k^{2}(^{2} + k^{2})(^{2} + 4k^{2})(9^{-2} + 4k^{2})}$$
(17)

which is obtained by inserting expression (16) in Eq. (10). Since the extra term (17) is always positive, all electronic states with  $k > k_c$  are exponentially localised with inverse localisation length proportional to the fourth power of the disorder strength,  $(k) / \pi^4$ .

The main conclusion of this study is that the delocalisation transition occurring in 1D models with long-range correlated disorder consists in a

change of the scaling behaviour of the Lyapunov exponent when the electronic energy crosses a critical threshold: more speci cally, the Lyapunov exponent, which is a quadratic function of the disorder strength in the localised phase, assumes a quartic form in the extended phase. A nother relevant remark is that non-G aussian potentials produce a stronger localisation e ect than their G aussian counterparts.

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